Toshiba Bi-CD Integrated Circuit Silicon Monolithic

# **TB6612FNG**

#### Driver IC for Dual DC motor

TB6612FNG is a driver IC for DC motor with output transistor in LD MOS structure with low ON-resistor. Two input signals, IN1 and IN2, can choose one of four modes such as CW, CCW, short brake, and stop mode.

# SSOP24-P-300-0.65A

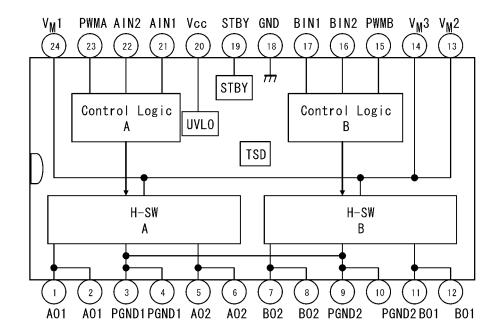
Weight: 0.14 g (typ.)

#### **Features**

- Power supply voltage: VM = 15 V(Max)
- Output current: IOUT = 1.2 A(ave)/3.2 A (peak)
- Output low ON resistor:  $0.5\Omega$  (upper+lower Typ. @ VM  $\geq 5$  V)
- Standby (Power save) system
- CW/CCW/short brake/stop function modes
- · Built-in thermal shutdown circuit and low voltage detecting circuit
- Small faced package(SSOP24: 0.65 mm Lead pitch)

\* This product has a MOS structure and is sensitive to electrostatic discharge. When handling this product, ensure that the environment is protected against electrostatic discharge by using an earth strap, a conductive mat and an ionizer. Ensure also that the ambient temperature and relative humidity are maintained at reasonable levels.

## **Block Diagram**



#### **Pin Functions**

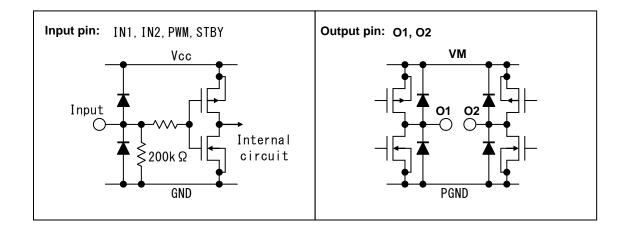
| No. | Pin Name | I/O | Function                                    |  |  |  |  |  |
|-----|----------|-----|---|--|--|--|--|--|
| 1   | AO1      |     | ch A output 1                               |  |  |  |  |  |
| 2   | AO1      | 0   | ch A output 1                               |  |  |  |  |  |
| 3   | PGND1    |     | Power GND 1                                 |  |  |  |  |  |
| 4   | PGND1    | _   | YOWER GIND T                                |  |  |  |  |  |
| 5   | AO2      | 0   | ch A output 2                               |  |  |  |  |  |
| 6   | AO2      | O   | ch A output 2                               |  |  |  |  |  |
| 7   | BO2      | 0   | ch B output 2                               |  |  |  |  |  |
| 8   | BO2      | Ü   |   |  |  |  |  |  |
| 9   | PGND2    |     | Power GND 2                                 |  |  |  |  |  |
| 10  | PGND2    |     | LOMBI GIAD 5                                |  |  |  |  |  |
| 11  | BO1      | 0   | ch B output 1                               |  |  |  |  |  |
| 12  | BO1      | Ŭ   | στο σαίραι τ                                |  |  |  |  |  |
| 13  | VM2      |     | Motor supply                                |  |  |  |  |  |
| 14  | VM3      |     | ινιοιοι συρριγ                              |  |  |  |  |  |
| 15  | PWMB     | I   | ch B PWM input/200 kΩ pull-down at internal |  |  |  |  |  |
| 16  | BIN2     | - 1 | ch B input 2/200 kΩ pull-down at internal   |  |  |  |  |  |
| 17  | BIN1     | I   | ch B input 1/200 kΩ pull-down at internal   |  |  |  |  |  |
| 18  | GND      | _   | Small signal GND                            |  |  |  |  |  |
| 19  | STBY     | I   | "L" = standby/200 kΩ pull-down at internal  |  |  |  |  |  |
| 20  | Vcc      | _   | Small signal supply                         |  |  |  |  |  |
| 21  | AIN1     | I   | ch A input 1/200 kΩ pull-down at internal   |  |  |  |  |  |
| 22  | AIN2     | I   | ch A input 2/200 kΩ pull-down at internal   |  |  |  |  |  |
| 23  | PWMA     | I   | ch A PWM input/200 kΩ pull-down at internal |  |  |  |  |  |
| 24  | VM1      | _   | Motor supply                                |  |  |  |  |  |

## Absolute Maximum Ratings (Ta = 25°C)

| Characteristics       | Symbol                  | Rating     | Unit | Remarks   |
|-----------------------|-------------------------|------------|------|---|
| Complexedtere         | VM                      | 15         | V    |   |
| Supply voltage        | Vcc                     | 6          |      |   |
| Input voltage         | V <sub>IN</sub>         | -0.2 to 6  | V    | IN1,IN2,STBY,PWM pins   |
| Output voltage        | Output voltage VouT     |            | V    | O1,O2 pins  |
|                       | lout                    | 1.2        |      | Per 1 ch  |
| Output current        | I <sub>OUT</sub> (peak) | 2          | А    | tw = 20 ms Continuous pulse, Duty ≤ 20%                       |
|                       |                         | 3.2        |      | tw = 10 ms Single pulse                                       |
|                       | P <sub>D</sub>          | 0.78       | W    | IC only   |
| Power dissipation     |                         | 0.89       |      | 50 mm × 50 mm t = 1.6 mm Cu ≥ 40% in PCB mounting             |
| i ower dissipation    |                         | 1.36       |      | 76.2 mm × 114.3 mm $t = 1.6$ mm Cu $\ge 30\%$ in PCB mounting |
| Operating temperature | T <sub>opr</sub>        | -20 to 85  | °C   |   |
| Storage temperature   | T <sub>stg</sub>        | -55 to 150 | °C   |   |

## Operating Range (Ta = -20 to 85°C)

| Characteristics       | Symbol | Min | Тур. | Max  | Unit | Remarks                                     |
|-----------------------|--------|-----|------|------|------|---|
| Cumply voltogo        | Vcc    | 2.7 | 3    | 5.5  | V    |   |
| Supply voltage        | VM     | 2.5 | 5    | 13.5 | V    |   |
|                       | lout   | 1   | 1    | 1.0  |      | VM ≥ 4.5 V                                  |
| Output current (H-SW) |        |     |      | 0.4  | Α    | 4.5 V > VM ≥ 2.5 V<br>Without PWM Operation |
| Switching frequency   | fpwm   | -   | -    | 100  | kHz  |   |

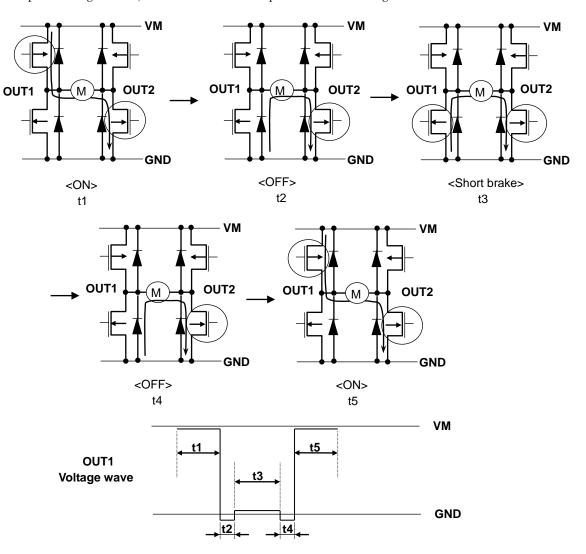


#### **H-SW Control Function**

| Input |     |     |      | Output                  |      |             |             |  |
|-------|-----|-----|------|-------------------------|------|-------------|-------------|--|
| IN1   | IN2 | PWM | STBY | OUT1                    | OUT2 | Mode        |             |  |
| н     | Н   | H/L | Н    | L                       | L    | Short brake |             |  |
| L H   | Н   |     | Н    | L                       | Н    | CCW         |             |  |
|       | П   | L H |      | L                       | L    | Short brake |             |  |
| Н     | L   | L   | Н    | Н                       | Н    | L           | CW          |  |
|       |     |     | L    | Н                       | L    | L           | Short brake |  |
| L     | L   | H   | Ħ    | OFF<br>(High impedance) |      | Stop        |             |  |
| H/L   | H/L | H/L | L    | OFF<br>(High impedance) |      | Standby     |             |  |

## **H-SW Operating Description**

• To prevent penetrating current, dead time t2 and t4 is provided in switching to each mode in the IC.



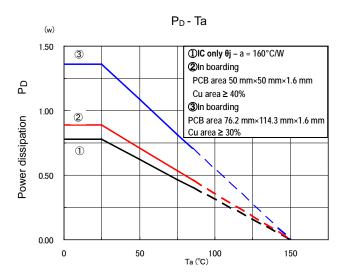


# Electrical Characteristics (unless otherwise specified, Ta = 25°C, Vcc = 3 V, VM = 5 V)

| Characteristics                                | Symbol   |        | Test Condition  | Min                     | Тур. | Max     | Unit |  |
|--|--|--------|---|-------------------------|------|---------|------|--|
|  | Icc(3 V)                                       |        | STBY = Vcc = 3 V, VM = 5 V                                    | _                       | 1.1  | 1.8     | mA   |  |
| 0  | Icc(5.5 V)                                     |        | STBY = Vcc = 5.5 V, VM = 5 V                                  | _                       | 1.5  | 2.2     |      |  |
| Supply current                                 | ICC(STB)                                       |        | CTDV 0.V  | _                       | 1    | 1       | μΑ   |  |
|  |  |        | STBY = 0 V  | _                       | 1    | 1       |      |  |
| Control inner treate no                        | V <sub>I</sub> H<br>V <sub>I</sub> L           |        |   | Vcc×0.7                 | 1    | Vcc+0.2 | ٧    |  |
| Control input voltage                          |  |        | _   | -0.2                    | _    | Vcc×0.3 |      |  |
| Ocataclian of comment                          | IIH  |        | V <sub>IN</sub> = 3 V   | 5                       | 15   | 25      |      |  |
| Control input current                          | I  | L      | V <sub>IN</sub> = 0 V   | _                       | _    | 1       | μΑ   |  |
| Otana illa sa baranta and tana kanana          | V <sub>IH</sub> (STB)<br>V <sub>IL</sub> (STB) |        |   | Vcc×0.7                 | _    | Vcc+0.2 | V    |  |
| Standby input voltage                          |  |        | _   | -0.2                    | _    | Vcc×0.3 |      |  |
| Otana dia dia manta adamana                    | l <sub>IH(</sub>                               | STB)   | V <sub>IN</sub> = 3 V   | 5                       | 15   | 25      |      |  |
| Standby input current                          | I <sub>IL(STB)</sub>                           |        | V <sub>IN</sub> = 0 V   | _                       | _    | 1 μΑ    |      |  |
| Output saturating voltage                      | V <sub>sat(U+L)1</sub>                         |        | I <sub>O</sub> = 1 A, Vcc = VM = 5 V                          |                         | 0.7  | V       |      |  |
| Output saturating voltage                      |  |        | $I_O = 0.3 \text{ A}, \text{ Vcc} = \text{ VM} = 5 \text{ V}$ | c = VM = 5 V — 0.15 0.2 |      | 0.21    | v    |  |
| Output lookage current                         | I <sub>L(U)</sub>                              |        | VM = V <sub>OUT</sub> = 15 V — — —                            |                         | 1    | ۸       |      |  |
| Output leakage current                         | I <sub>L(L)</sub>                              |        | VM = 15 V, V <sub>OUT</sub> = 0 V                             |                         | _    | _       | μΑ   |  |
| Dogoporative diade \/C                         | V <sub>F(U)</sub>                              |        | I- 1A   | _                       | 1    | 1.1     | V    |  |
| Regenerative diode VF                          |  |        | I <sub>F</sub> = 1A   | _                       | 1    | 1.1     |      |  |
| Low voltage detecting voltage                  | UVLD   |        | (Design target only)  | _                       | 1.9  |         |      |  |
| Recovering voltage                             | UVLC   |        |   | _                       | 2.2  | _       |      |  |
|  | t <sub>r</sub>                                 |        | (Danisa tanan tank)   | _                       | 24   | _       |      |  |
| Dannana anaad                                  |  |        | (Design target only)  | _                       | 41   | _       |      |  |
| Response speed                                 | Dead   | H to L | Penetration protect time                                      |                         | 50   |         | ns   |  |
|  | time   | L to H | (Design target only)  | _                       | 230  | _       |      |  |
| Thermal shutdown circuit operating temperature | ng temperature TSD nal shutdown                |        | (Design target only)  |                         | 175  |         | °C   |  |
| Thermal shutdown hysteresis                    |  |        | (Design target only)  | _                       | 20   | _       |      |  |

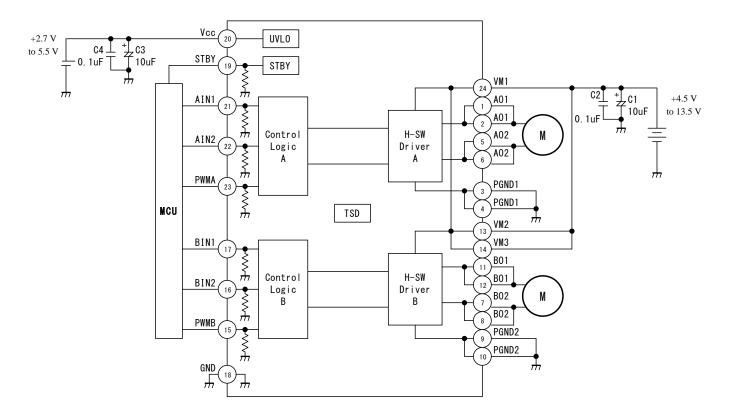


## **Target characteristics**





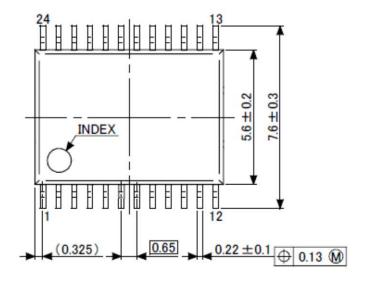
## **Typical Application Diagram**



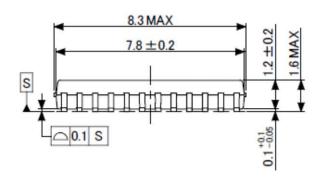
Note: Condensers for noise absorption (C1, C2, C3, and C4) should be connected as close as possible to the IC.

## **Package Dimennsions**

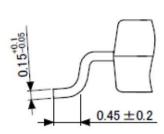
SSOP24-P-300-0.65A "Unit: mm"







#### Detail of a terminal



Weght: 0.14 g (typ)

#### **Notes on Contents**

#### 1. Block Diagrams

Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.

#### 2. Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

#### 3. Timing Charts

Timing charts may be simplified for explanatory purposes.

#### 4. Application Circuits

The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially at the mass production design stage.

Toshiba does not grant any license to any industrial property rights by providing these examples of application circuits.

#### 5. Test Circuits

Components in the test circuits are used only to obtain and confirm the device characteristics. These components and circuits are not guaranteed to prevent malfunction or failure from occurring in the application equipment.

### IC Usage Considerations Notes on handling of ICs

- [1] The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.

  Exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.
- [2] Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of over current and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke or ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- [3] If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. IC breakdown may cause injury, smoke or ignition.
  - Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- [4] Do not insert devices in the wrong orientation or incorrectly.
  - Make sure that the positive and negative terminals of power supplies are connected properly.
  - Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.
  - In addition, do not use any device that is applied the current with inserting in the wrong orientation or incorrectly even just one time.

#### Points to remember on handling of ICs

#### (1) Thermal Shutdown Circuit

Thermal shutdown circuits do not necessarily protect ICs under all circumstances. If the thermal shutdown circuits operate against the over temperature, clear the heat generation status immediately.

Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the thermal shutdown circuit to not operate properly or IC breakdown before operation.

#### (2) Heat Radiation Design

In using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (Tj) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into considerate the effect of IC heat radiation with peripheral components.

#### (3) Back-EMF

When a motor rotates in the reverse direction, stops or slows down abruptly, a current flow back to the motor's power supply due to the effect of back-EMF. If the current sink capability of the power supply is small, the device's motor power supply and output pins might be exposed to conditions beyond absolute maximum ratings. To avoid this problem, take the effect of back-EMF into consideration in system design.



#### **RESTRICTIONS ON PRODUCT USE**

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
  EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
  MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
  ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
  limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, equipment used for
  automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions,
  safety devices, elevators and escalators, devices related to electric power, and equipment used in finance-related fields. IF YOU USE
  PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
  TOSHIBA sales representative.
- · Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
  applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
  FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
  WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
  LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
  LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
  SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
  FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
   Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
   OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Seeed Studio: 108020103